16-bit bus transceiver; 3-state Rev. 1 — 10 April 2017

Product data sheet

nexperia

1 General description

The 74ABT16245B-Q100 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT16245B-Q100 device is a dual octal transceiver featuring non-inverting 3state bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features two output enable ($1\overline{OE}$, $2\overline{OE}$) inputs for easy cascading and two direction (1DIR, 2DIR) inputs for direction control.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 3) and is suitable for use in automotive applications.

2 Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 3)
 Specified from -40 °C to +85 °C
- 16-bit bidirectional bus interface
- Multiple V_{CC} and GND pins minimize switching noise
- Power-up 3-state
- 3-state buffers
- Output capability: +64 mA / -32 mA
- Live insertion/extraction permitted
- · Latch-up performance: JESD 78 Class II
- ESD protection:
 - HBM JESD22-A114E exceeds 2000 V
 - CDM JESD22-C101C exceeds 1000 V

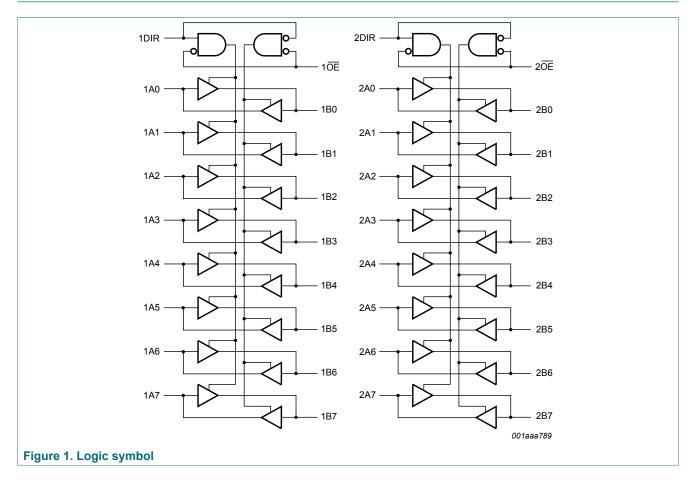
3 Ordering information

Table 1. Ordering information

| Type number | Package | | | | | | |
|---------------------|----------------------|---------|---|----------|--|--|--|
| | Temperature range | Name | Description | Version | | | |
| 74ABT16245BDGG-Q100 | -40 °C to +85 °C | TSSOP48 | plastic thin shrink small outline package; 48 leads; body width 6.1 mm | SOT362-1 | | | |

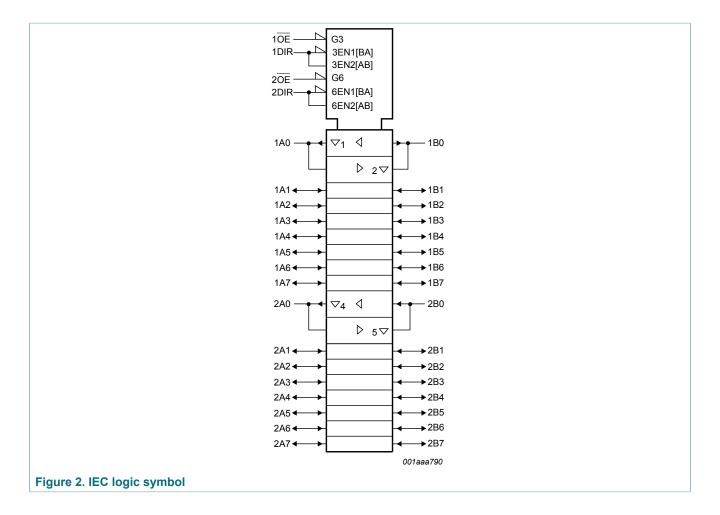
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4 Functional diagram



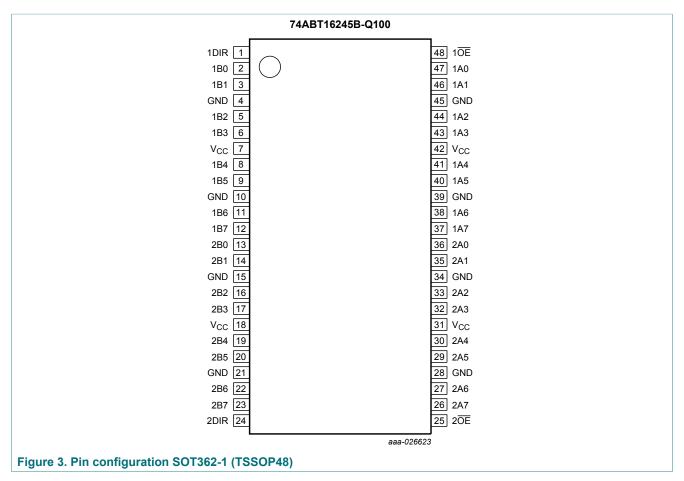
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5 Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

| Symbol | Pin | Description |
|---------------------------|--------------------------------|----------------------------------|
| 1DIR, 2DIR | 1, 24 | direction control input |
| 1B0 to 1B7 | 2, 3, 5, 6, 8, 9, 11, 12 | data input/output |
| 2B0 to 2B7 | 13, 14, 16, 17, 19, 20, 22, 23 | data input/output |
| GND | 4, 10, 15, 21, 28, 34, 39, 45 | ground (0 V) |
| V _{CC} | 7, 18, 31, 42 | supply voltage |
| 1 <u>0E</u> , 2 <u>0E</u> | 48, 25 | output enable input (active LOW) |
| 1A0 to 1A7 | 47, 46, 44, 43, 41, 40, 38, 37 | data input/output |
| 2A0 to 2A7 | 36, 35, 33, 32, 30, 29, 27, 26 | data input/output |

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6 Functional description

Table 3. Function table ^[1]

| Inputs | | Outputs | | |
|--------|------|-----------|-----------|--|
| nOE | nDIR | nAn | nBn | |
| L | L | nAn = nBn | inputs | |
| L | Н | inputs | nBn = nAn | |
| Н | Х | Z | Z | |

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

Z = high-impedance OFF-state.

7 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|-----------------------------------|-----|------|------|------|
| V _{CC} | supply voltage | | | -0.5 | +7.0 | V |
| VI | input voltage | | [1] | -1.2 | +7.0 | V |
| Vo | output voltage | output in OFF-state or HIGH-state | [1] | -0.5 | +5.5 | V |
| I _{IK} | input clamping current | V _I < 0 V | | -18 | - | mA |
| I _{ОК} | output clamping current | V _O < 0 V | | -50 | - | mA |
| I _O | output current | output in LOW-state | | - | 128 | mA |
| | | output in HIGH-state | | -64 | - | mA |
| Tj | junction temperature | | [2] | - | 150 | °C |
| T _{stg} | storage temperature | | | -65 | +150 | °C |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

8 Recommended operating conditions

Table 5. Operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Мах | Unit |
|------------------|-------------------------------------|-------------|-----|-----------------|------|
| V _{CC} | supply voltage | | 4.5 | 5.5 | V |
| VI | input voltage | | 0 | V _{CC} | V |
| V _{IH} | HIGH-level input voltage | | 2.0 | - | V |
| V _{IL} | LOW-level input voltage | | - | 0.8 | V |
| I _{OH} | HIGH-level output current | | -32 | - | mA |
| I _{OL} | LOW-level output current | | - | 64 | mA |
| Δt/ΔV | input transition rise and fall rate | | - | 10 | ns/V |
| T _{amb} | ambient temperature | in free air | -40 | +85 | °C |

9 Static characteristics

Table 6. Static characteristics

| Symbol | Parameter | Conditions | | 25 °C | | | -40 °C t | Unit | |
|-----------------------|---|--|-----|-------|-------|------|----------|------|----|
| | | | | Min | Тур | Max | Min | Мах | |
| V _{IK} | input clamping voltage | V _{CC} = 4.5 V; I _{IK} = -18 mA | | -1.2 | -0.9 | - | -1.2 | - | V |
| V _{OH} | HIGH-level | $V_{I} = V_{IL} \text{ or } V_{IH}$ | | | | | | | |
| | output voltage | V _{CC} = 4.5 V; I _{OH} = -3 mA | | 2.5 | 2.9 | - | 2.5 | - | V |
| | | V _{CC} = 5.0 V; I _{OH} = -3 mA | | 3.0 | 3.4 | - | 3.0 | - | V |
| | | V _{CC} = 4.5 V; I _{OH} = -32 mA | | 2.0 | 2.4 | - | 2.0 | - | V |
| V _{OL} | LOW-level output voltage | V_{CC} = 4.5 V; I_{OL} = 64 mA; V_{I} = V_{IL} or V_{IH} | | - | 0.42 | 0.55 | - | 0.55 | V |
| I | input leakage current | control pins; V_{CC} = 5.5 V; V _I = V _{CC} or GND | | - | ±0.01 | ±1.0 | - | ±1.0 | μA |
| I _{OFF} | power-off leakage current | V_{CC} = 0 V; V_{I} or $V_{O} \le 4.5$ V | | - | ±5.0 | ±100 | - | ±100 | μA |
| I _{O(pu/pd)} | power-up/ power-down output current | V_{CC} = 2.0 V; V_{O} = 0.5 V; V _I = GND or V _{CC} ; nOE = HIGH | [1] | - | ±5.0 | ±50 | - | ±50 | μA |
| I _{OZ} | OFF-state | V_{CC} = 5.5 V; V_{I} = V_{IL} or V_{IH} | | | | | | | |
| | output current | output HIGH-state at V_0 = 5.5 V | | - | 0.1 | 10 | - | 10 | μA |
| | | output LOW-state at $V_0 = 0 V$ | | - | -0.1 | -10 | - | -10 | μA |
| I _{CEX} | output high leakage current | HIGH-state; V_0 = 5.5 V; V_{CC} = 5.5 V; V _I = GND or V _{CC} | | - | 5.0 | 50 | - | 50 | μA |
| I _O | output current | $V_{CC} = 5.5 \text{ V}; V_O = 2.5 \text{ V}$ ^[2] | | -50 | -92 | -180 | -50 | -180 | mA |
| I _{CC} | supply current | V_{CC} = 5.5 V; V_{I} = GND or V_{CC} | | | | | | | |
| | | outputs HIGH-state | | - | 0.30 | 0.7 | - | 0.7 | mA |

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| Symbol | Parameter | er Conditions | | 25 °C | | | o +85 °C | Unit |
|------------------|-----------------------------|--|-----|-------|-----|-----|----------|------|
| | | | Min | Тур | Max | Min | Мах | |
| | | outputs LOW-state | - | 10 | 19 | - | 19 | mA |
| | | outputs 3-state | - | 0.30 | 0.7 | - | 0.7 | mA |
| | | per input pin; V _{CC} = 5.5 V; one data input at 3.4 V and other inputs at V _{CC} or GND | [3] | | | | | |
| | | outputs enabled | - | 400 | 700 | - | 700 | μA |
| | | outputs disabled | - | 100 | 250 | - | 250 | μA |
| | | control pins; outputs disabled; one enable input at 3.4 V and other inputs at V_{CC} or GND | - | 400 | 700 | - | 700 | μA |
| CI | input capacitance | V _I = 0 V or V _{CC} | | 4 | - | - | - | pF |
| C _{I/O} | input/output capacitance | outputs disabled; $V_O = 0 V \text{ or } V_{CC}$ | | 7 | - | - | - | pF |

[1] This parameter is valid for any V_{CC} between 0 V and 2.1 V, with a transition time of up to 10 ms. From V_{CC} = 2.1 V to V_{CC} = 5 V ± 10 %, a transition time of up to 100 µs is permitted.

[2] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

 $\label{eq:constraint} [3] \qquad \mbox{This is the increase in supply current for each input at 3.4 V}.$

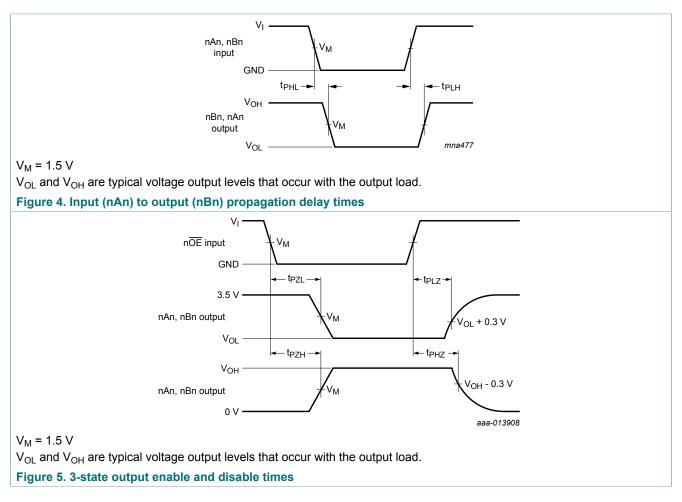
10 Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V. For test circuit, see Figure 6.

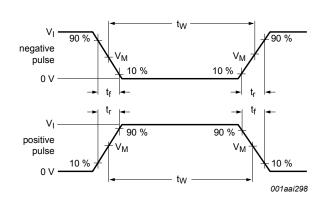
| Symbol | I Parameter Conditions | | 25 °C; V _{CC} = 5.0 V | | | -40 °C to V _{CC} = 5.0 | Unit | |
|------------------|-------------------------------------|---|-----------------------------------|-----|-----|------------------------------------|------|----|
| | | | Min | Тур | Мах | Min | Мах | |
| t _{PLH} | LOW to HIGH propagation delay | nAn to nBn; see <u>Figure 4</u> | 1.0 | 2.0 | 3.2 | 1.0 | 3.5 | ns |
| t _{PHL} | HIGH to LOW propagation delay | nAn to nBn; see <u>Figure 4</u> | 1.0 | 2.3 | 3.5 | 1.0 | 4.0 | ns |
| t _{PZH} | OFF-state to HIGH propagation delay | nOE to nAn or nBn; see <u>Figure 5</u> | 1.0 | 3.0 | 4.4 | 1.0 | 5.1 | ns |
| t _{PZL} | OFF-state to LOW propagation delay | nOE to nAn or nBn; see <u>Figure 5</u> | 1.7 | 4.0 | 5.2 | 1.7 | 6.1 | ns |
| t _{PHZ} | HIGH to OFF-state propagation delay | nOE to nAn or nBn; see <u>Figure 5</u> | 1.7 | 3.5 | 4.9 | 1.7 | 5.4 | ns |
| t _{PLZ} | LOW to OFF-state propagation delay | n OE to nAn or nBn; see <u>Figure 5</u> | 1.5 | 3.2 | 4.4 | 1.5 | 5.0 | ns |

10.1 Waveforms and test circuit



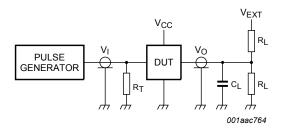
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V_M = 1.5 V

a.Input pulse definition



Test data is given in Table 8.

Definitions test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

b.Test circuit

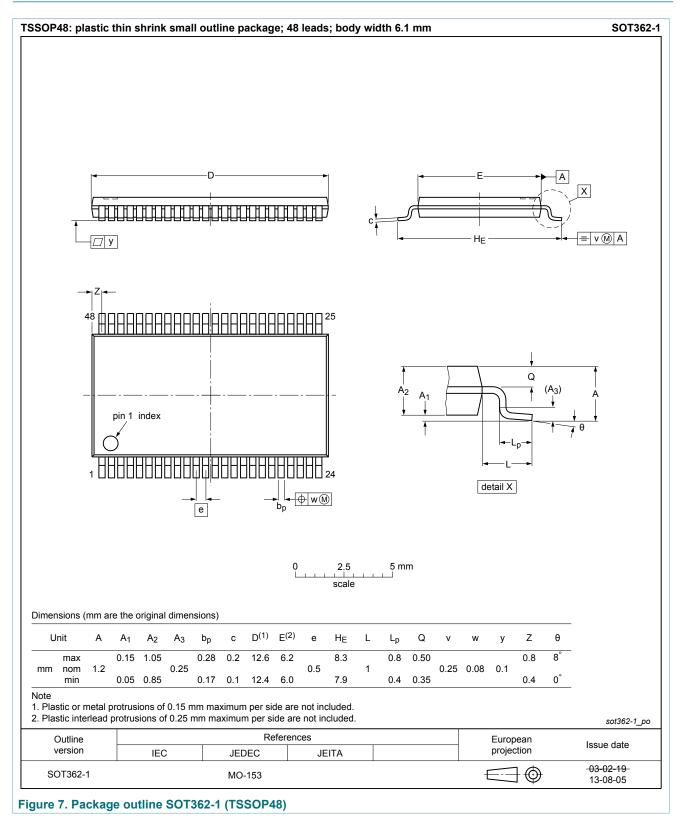
Figure 6. Test circuit for measuring switching times

Table 8. Test data

| Input | | | Load | | V _{EXT} | | | |
|-------|-------|--------|---------------------------------|-------|------------------|-------------------------------------|-------------------------------------|-------------------------------------|
| VI | fi | tw | t _r , t _f | CL | RL | t _{PHZ} , t _{PZH} | t _{PLZ} , t _{PZL} | t _{PLH} , t _{PHL} |
| 3.0 V | 1 MHz | 500 ns | 2.5 ns | 50 pF | 500 Ω | open | 7.0 V | open |

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11 Package outline



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12 Abbreviations

| Table 9. Abbreviations | | | | | |
|------------------------|---|--|--|--|--|
| Acronym | Description | | | | |
| BiCMOS | Bipolar Complementary Metal Oxide Semiconductor | | | | |
| CDM | Charged Device Model | | | | |
| DUT | Device Under Test | | | | |
| ESD | ElectroStatic Discharge | | | | |
| НВМ | Human Body Model | | | | |

13 Revision history

| Table 10. Revision history | | | | |
|----------------------------|--------------|--------------------|---------------|------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| 74ABT16245B_Q100 v.1 | 20170410 | Product data sheet | - | - |

14 Legal information

14.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
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